

2729-125

125 Watts, 36 Volts, 100µs, 10% Radar 2700-2900 MHz

> CASE OUTLINE 55KS-1

Common Base

GENERAL DESCRIPTION

The 2729-125 is an internally matched, COMMON BASE bipolar transistor capable of providing 125 Watts of pulsed RF output power at 100µs pulse width, 10% duty factor across the 2700 to 2900 MHz band. The transistor prematch and test fixture has been optimized through the use of Pulsed Automated Load Pull. This hermetically solder-sealed transistor is specifically designed for S-band radar applications. It utilizes gold metallization and emitter ballasting to provide high reliability and supreme ruggedness.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation	
Device Dissipation @ 25°C ¹	350 W
Maximum Voltage and Current	
Collector to Base Voltage (BVces)	65 V
Emitter to Base Voltage (BV _{ebo})	3.0 V
Collector Current (I _c)	15 A
Maximum Temperatures	
Storage Temperature -6	55 to +200 °C
Operating Junction Temperature	+200 °C

ELECTRICAL CHARACTERISTICS @ 25°C

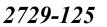
SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Pout	Power Output	F=2700-2900 MHz	125			W
P _{in}	Power Input	$V_{cc} = 36$ Volts			15.7	W
Pg	Power Gain	Pulse Width = $100 \ \mu s$	9.0	9.5		dB
η _c	Collector Efficiency	Duty Factor = 10%	45	55		%
VSWR	Load Mismatch Tolerance ¹	$F = 2900 \text{ MHz}, P_0 = 125 \text{W}$			2:1	

FUNCTIONAL CHARACTERISTICS @ 25°C

BV _{ebo}	Emitter to Base Breakdown	Ie = 30 mA	3.0			V
BV _{ces}	Collector to Emitter Breakdown	Ic = 120 mA	56	65		V
\mathbf{h}_{FE}	DC – Current Gain	Vce = 5V, Ic = 600 mA	18	50		
θjc ¹	Thermal Resistance				0.5	°C/W

NOTE: 1. At rated output power and pulse conditions

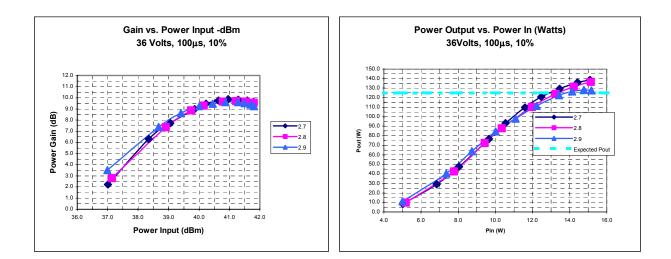
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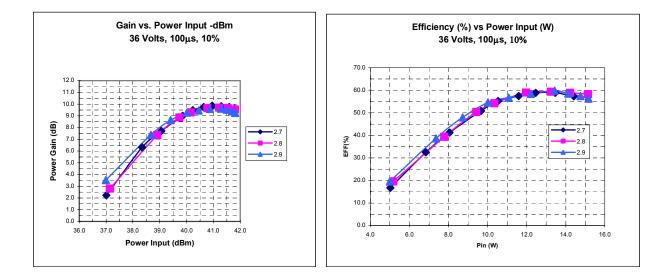




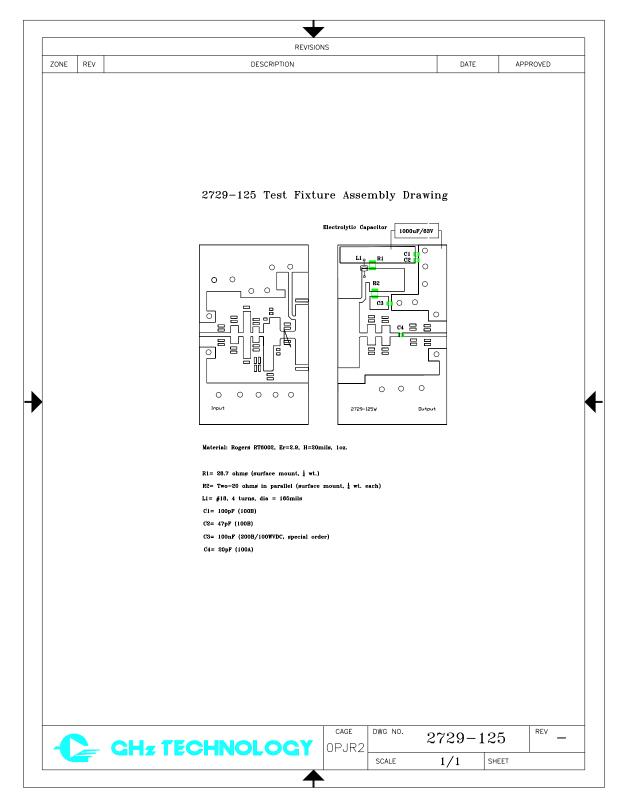
Vcc = 36 Volts, Pulse Width = 100µs, Duty = 10%

G2747-2, Unit 7, TF040803P2





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